



Changshu Talent
Semiconductors Co.,Ltd
Tel:0086-512-52851998
Fax:0086-512-52153129

BAT54 THRU BAT54S

Features

- Low Forward Voltage
- Surface Mount device
- Epoxy meets UL 94 V-0 flammability rating
- Moisture Sensitivity Level 1

Number	Device Marking		Type	Pin Configuration See page 3
	1	2		
BAT54	KL1	L4	Single	Figure 1
BAT54A	KL2	L42	Dual	Figure 2
BAT54C	KL3	L43	Dual	Figure 3
BAT54S	KL4	L44	Dual	Figure 4

Maximum Ratings

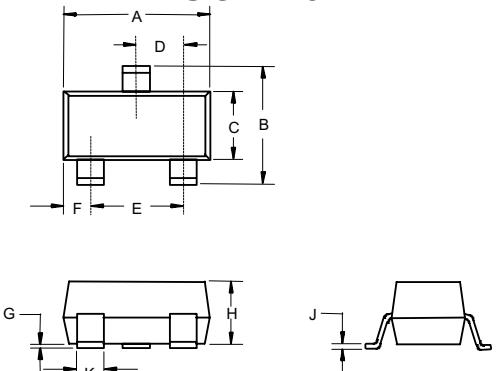
Continuos Reverse Voltage	V_R	30V
Forward ContinuousCurrent	I_F	200mA
Non-Repetitive Peak Forward Current $t < 1s$	$I_{F\text{SM}}$	0.6A
Total Power Dissipation @ $T_A = 25^\circ\text{C}$	P_D	200mW
Storage Temperature Range	T_{stg}	-55°C to 150°C
Operating Junction Temperature Range	T_j	-55°C to 125°C
Soldering temperature during 10s	T	260°C

Electrical Characteristics @ 25 °C Unless Otherwise Specified

Characteristics	Symbol	Max.	Notes
Forward Voltage at $I_F = 0.1\text{mA}$		240mV	
$I_F = 1\text{mA}$	V_F	320mV	
$I_F = 10\text{mA}$		400mV	
$I_F = 30\text{mA}$		500mV	
$I_F = 100\text{mA}$		1000mV	
Reverse Current	I_R	2.0 uA	$V_R = 25\text{V}$
Capacitance	C_J	10pF	Measured at 1.0MHz, $V_R=1.0\text{V}$
Reverse Recovery Time	t_{rr}	5nS	$I_F=I_R=10\text{mA}$; $I_{(REC)} = 1\text{mA}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	500°C/W	

200mWatt, 30Volt Schottky Barrier Diode

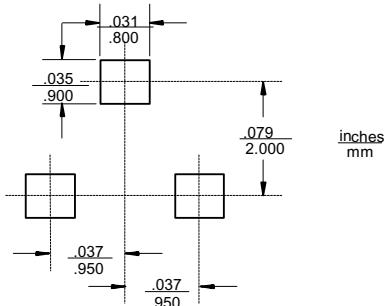
SOT-23



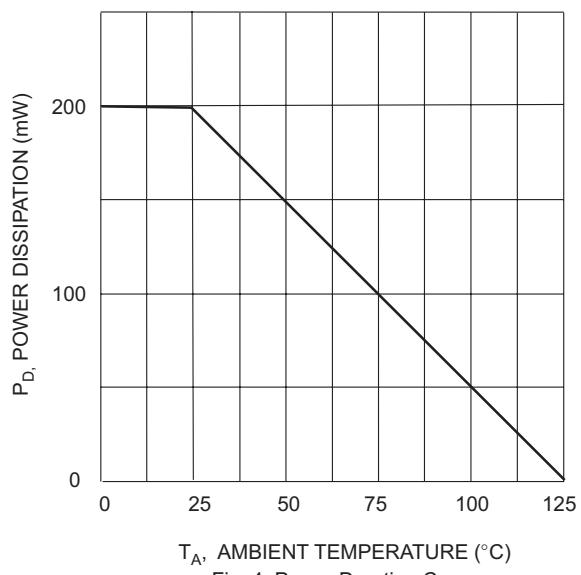
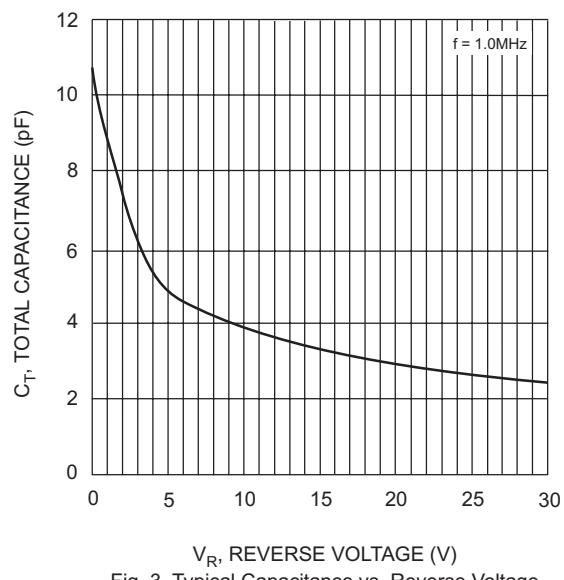
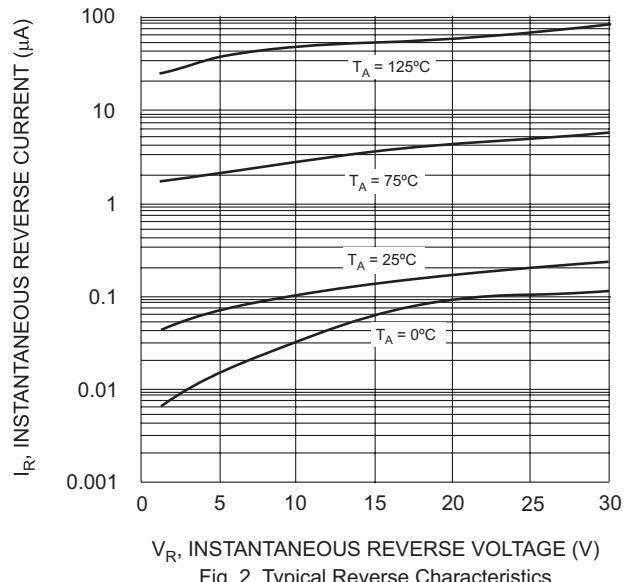
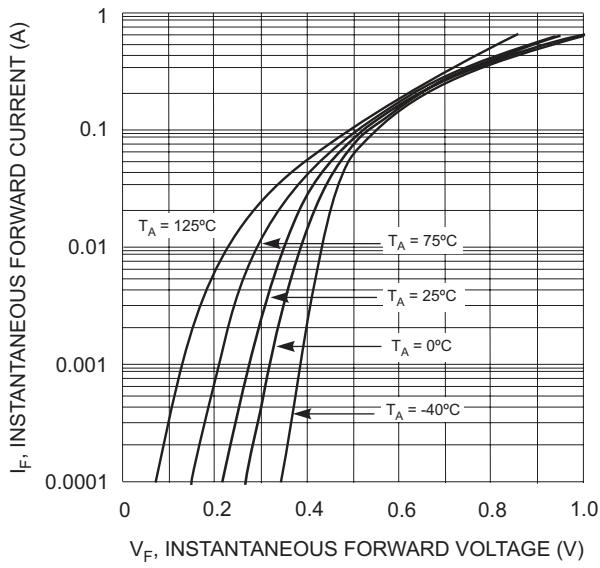
DIMENSIONS

DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.110	.120	2.80	3.04	
B	.083	.104	2.10	2.64	
C	.047	.055	1.20	1.40	
D	.035	.041	.89	1.03	
E	.070	.081	1.78	2.05	
F	.018	.024	.45	.60	
G	.0005	.0039	.013	.100	
H	.035	.044	.89	1.12	
J	.003	.007	.085	.180	
K	.015	.020	.37	.51	

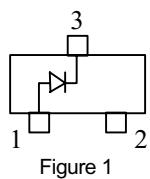
Suggested Solder Pad Layout



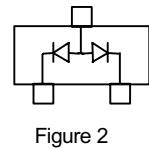
BAT54 thru BAT54S



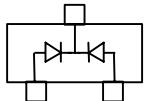
Pin Configuration - Top View



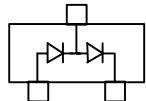
BAT54



BAT54A



BAT54C



BAT54S